

# DMPH4013SPSQ 175°C 40V P-CHANNEL ENHANCEMENT MODE MOSFET PowerDI5060-8

### **Product Summary**

BV <sub>DSS</sub>	RDS(ON) Max	I⊳ Tc = +25°C
-40V	13mΩ @ V <sub>GS</sub> = -10V	-69A
-40 V	23mΩ @ V <sub>GS</sub> = -4.5V	-52A

# **Description and Applications**

This MOSFET is designed to meet the stringent requirements of automotive applications. It is qualified to AEC-Q101, supported by a PPAP and is ideal for use in:

- Reverse polarity protections
- BLDC motor controls
- Power-management functions

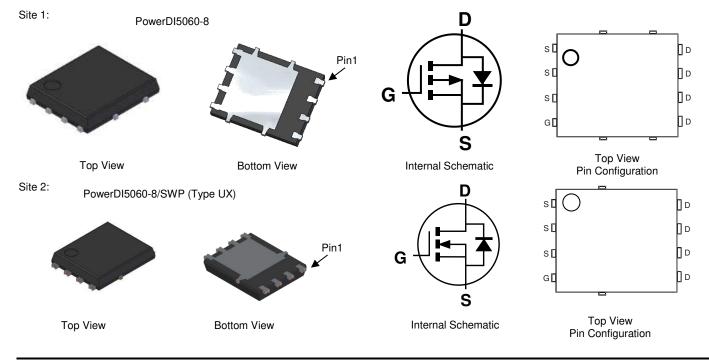
### **Features and Benefits**

- Rated to +175°C Ideal for High Ambient Temperature Environments
- 100% Unclamped Inductive Switch (UIS) Test in Production
- Low On-Resistance
- Fast Switching Speed
- Lead-Free Finish; RoHS Compliant (Notes 1 & 2)
- Halogen and Antimony Free. "Green" Device (Note 3)
- The DMPH4013SPSQ is suitable for automotive applications requiring specific change control; this part is AEC-Q101 qualified, PPAP capable, and manufactured in IATF 16949 certified facilities.

https://www.diodes.com/quality/product-definitions/

# **Mechanical Data**

- Package: PowerDI<sup>®</sup>5060-8
- Package Material: Molded Plastic, "Green" Molding Compound. UL Flammability Classification Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020
- Terminal Connections: See Diagram
- Terminals: Finish 100% Matte Tin Annealed over Copper Leadframe. Solderable per MIL-STD-202, Method 208<sup>(3)</sup>
- Weight: 0.097 grams (Approximate)



# Ordering Information (Note 4)

Part Number	Package	Packing		
Fait Nulliber	Fackage	Qty.	Carrier	
DMPH4013SPSQ-13	PowerDI5060-8	2,500	Tape & Reel	
DMPH4013SPSQ-13	PowerDI5060-8/SWP (Type UX)	2,500	Tape & Reel	

Notes: 1. EU Directive 2002/95/EC (RoHS), 2011/65/EU (RoHS 2) & 2015/863/EU (RoHS 3) compliant. All applicable RoHS exemptions applied.

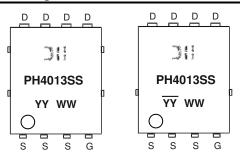
2. See https://www.diodes.com/quality/lead-free/ for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and Lead-free.

3. Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.

4. For packaging details, go to our website at https://www.diodes.com/design/support/packaging/diodes-packaging/.



# **Marking Information**



⊃¦¦ = Manufacturer's Marking PH4013SS = Product Type Marking Code YYWW = Date Code Marking YY or  $\overline{YY}$  = Year (ex: 23 = 2023) WW = Week (01 to 53)

# Maximum Ratings (@T<sub>A</sub> = +25°C, unless otherwise specified.)

Characteristic			Symbol	Value	Unit
Drain-Source Voltage			VDSS	-40	V
Gate-Source Voltage			Vgss	±20	V
Continuous Drain Current V <sub>GS</sub> = -10V (Note 7) State $T_C = +25^{\circ}C$ State $T_C = +100^{\circ}C$			ID	-69 -49	А
Pulsed Drain Current (10µs Pulse, Duty Cycle = 1%)			ldм	-277	A
Maximum Body Diode Continuous Current (Note 7)			ls	-69	A
Pulsed Source Current (10µs Pulse, Duty Cycle = 1%)			lsм	-277	А
Avalanche Current (Note 8) L = 1mH			las	-22	A
Avalanche Energy (Note 8) L = 1mH			E <sub>AS</sub>	260	mJ

### Thermal Characteristics (@TA = +25°C, unless otherwise specified.)

Characteristic		Symbol	Value	Unit
Total Power Dissipation (Note 5)	TA = +25°C	PD	1.5	W
Thermal Resistance, Junction to Ambient (Note 5)	Steady State	Reja	98	°C/W
Total Power Dissipation (Note 6)	T <sub>A</sub> = +25°C	PD	3.3	W
Thermal Resistance, Junction to Ambient (Note 6)	Steady State	Reja	45	°C/W
Thermal Resistance, Junction to Case (Note 7)		Rejc	1.6	°C/W
Operating and Storage Temperature Range		TJ, TSTG	-55 to +175	°C

5. Device mounted on FR-4 PC board, with minimum recommended pad layout, single sided. Notes:

Device mounted on FR-4 substrate PC board, 2oz copper, with thermal bias to bottom layer 1inch square copper plate.
Thermal resistance from junction to soldering point (on the exposed drain pad).

8. I<sub>AS</sub> and E<sub>AS</sub> ratings are based on low frequency and duty cycles to keep  $T_J$  = +25°C.



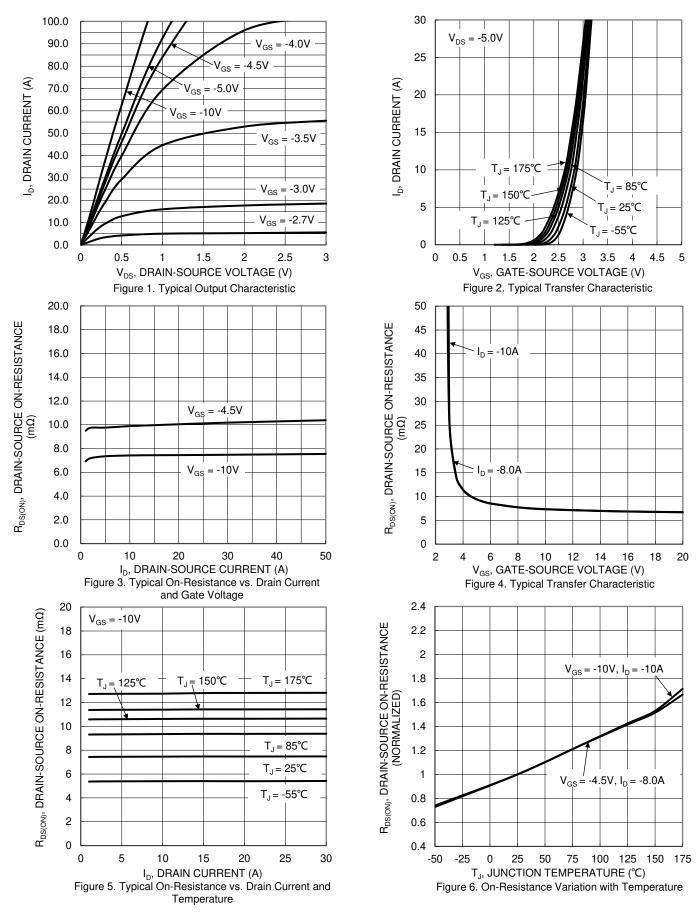
# Electrical Characteristics (@TA = +25°C, unless otherwise specified.)

Characteristic	Symbol	Min	Typ	Max	Unit	Test Condition
OFF CHARACTERISTICS (Note 9)	Symbol	IVIIA	Тур	wax	Unit	Test Condition
	DV/	40			V	
Drain-Source Breakdown Voltage	BVDSS	-40			V	$V_{GS} = 0V, I_D = -250\mu A$
Zero Gate Voltage Drain Current	IDSS	_	—	-1	μA	$V_{DS} = -40V, V_{GS} = 0V$
Gate-Source Leakage	lgss	_	—	±100	nA	$V_{GS} = \pm 20V, V_{DS} = 0V$
ON CHARACTERISTICS (Note 9)				-		-
Gate Threshold Voltage	VGS(TH)	-1	-1.8	-3	V	$V_{DS} = V_{GS}$ , $I_D = -250 \mu A$
Static Drain-Source On-Resistance	Bacon		9	13	mΩ	$V_{GS} = -10V, I_{D} = -10A$
Static Drain-Source On-nesistance	RDS(ON)	_	12.4	23	11152	$V_{GS} = -4.5V, I_D = -8A$
Diode Forward Voltage	Vsd	_	-0.70	-1.2	V	$V_{GS} = 0V$ , $I_{S} = -1A$
DYNAMIC CHARACTERISTICS (Note 10)						
Input Capacitance	Ciss	_	4763	—		$V_{DS} = -20V, V_{GS} = 0V$ f = 1MHz
Output Capacitance	Coss	_	539	—	pF	
Reverse Transfer Capacitance	Crss	—	403	—		
Gate Resistance	Rg	_	7.4	—	Ω	$V_{DS} = 0V, V_{GS} = 0V, f = 1MHz$
Total Gate Charge (V <sub>GS</sub> = -4.5V)	Qg	—	39	—		
Total Gate Charge (V <sub>GS</sub> = -10V)	Qg	—	87	—	nC	$V_{DS} = -20V,$ $I_D = -10A$
Gate-Source Charge	Qgs	_	12.5	—	no	
Gate-Drain Charge	Q <sub>gd</sub>	_	15	—		
Turn-On Delay Time	td(ON)		6.2			
Turn-On Rise Time	t <sub>R</sub>		4.8		ns	$\label{eq:VGS} \begin{array}{l} V_{GS} = -10V, \ V_{DD} = -20V, \\ R_G = 3\Omega, \ I_D = -10A \end{array}$
Turn-Off Delay Time	tD(OFF)		126	_		
Turn-Off Fall Time	tF		57	_		
Reverse Recovery Time	t <sub>RR</sub>	—	27	—	ns	I <sub>F</sub> = -10A, di/dt = -100A/μs
Reverse Recovery Charge	Qrr		21	_	nC	IF = -10A, di/dt = -100A/µs

Notes:9. Short duration pulse test used to minimize self-heating effect.10. Guaranteed by design. Not subject to product testing.

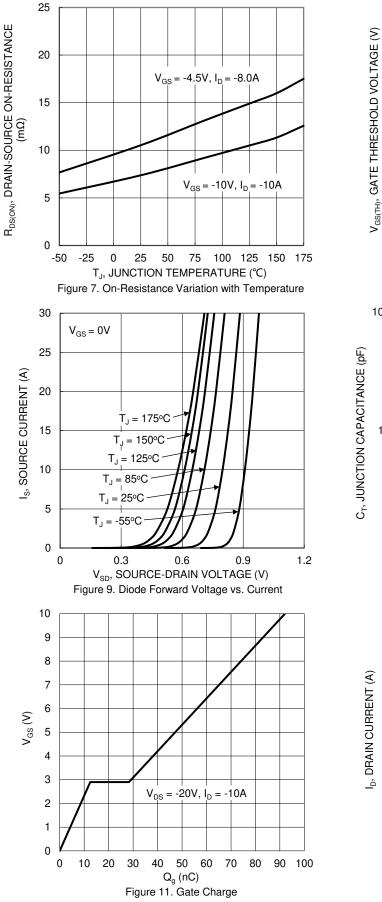


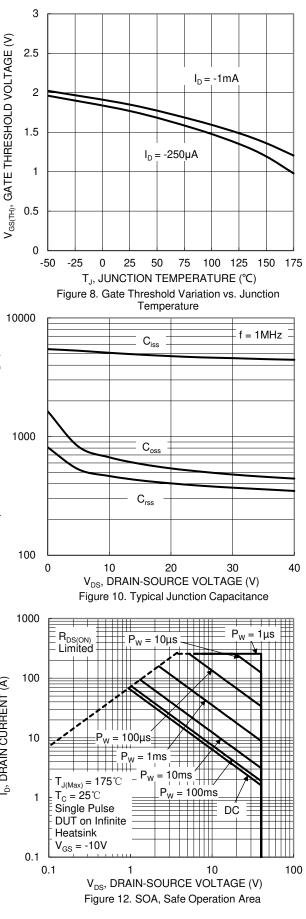
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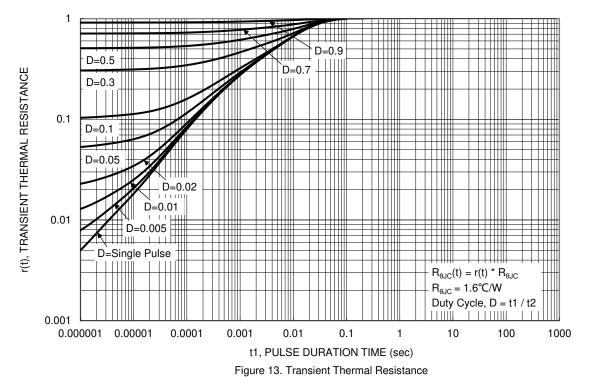
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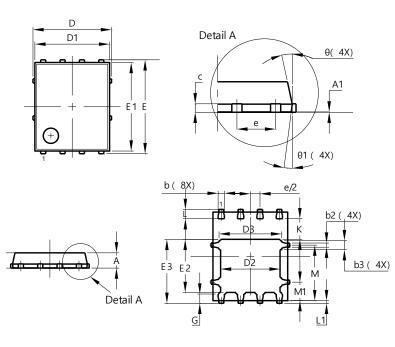


# **Package Outline Dimensions**

Please see http://www.diodes.com/package-outlines.html for the latest version.

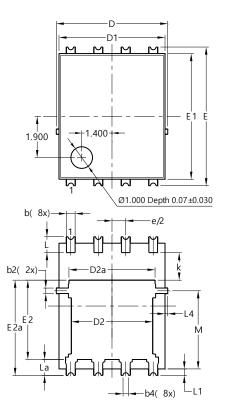
Site 1:

PowerDI5060-8

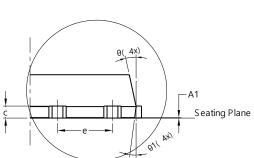


	PowerDI5060-8				
Dim	Min	Max	Тур		
Α	0.90	1.10	1.00		
A1	0.00	0.05	-		
b	0.33	0.51	0.41		
b2	0.200	0.350	0.273		
b3	0.40	0.80	0.60		
С	0.230	0.330	0.277		
D	ļ	5.15 BSC			
D1	4.70	5.10	4.90		
D2	3.70	4.10	3.90		
D3	3.90	4.30	4.10		
E	6.15 BSC				
E1	5.60	6.00	5.80		
E2	3.28	3.68	3.48		
E3	3.99	4.39	4.19		
е		1.27 BSC			
G	0.51	0.71	0.61		
K	0.51	-	-		
L	0.51	0.71	0.61		
L1	0.100	0.200	0.175		
М	3.235	4.035	3.635		
M1	1.00	1.40	1.21		
Θ	10°	12°	11°		
<b>Θ</b> 1	6°	8°	7°		
Al	All Dimensions in mm				

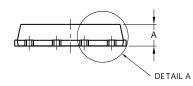
Site 2:



PowerDI5060-8/SWP (Type UX)



DETAIL A



PowerDI5060-8/SWP				
(Type UX)				
Dim	Min	Max	Тур	
Α	0.90	1.10	1.00	
A1	0	0.05		
b	0.30	0.50	0.41	
b2	0.20	0.35	0.25	
b4	(	).25REF	=	
С	0.230	0.330	0.277	
D		.15 BS0		
D1	4.70	5.10	4.90	
D2	3.56	3.96	3.76	
D2a	3.78	4.18	3.98	
Е	6	6.40 BS0	0	
E1	5.60	6.00	5.80	
E2	3.46	3.86	3.66	
E2a	4.195	4.595	4.395	
е		1.27BSC	)	
k	1.05			
L	0.635	0.835	0.735	
La	0.635	0.835	0.735	
L1	0.200	0.400	0.300	
L1a	0	.050RE		
L4	0.025	0.225	0.125	
М	3.205	4.005	3.605	
θ	10°	12°	11°	
θ1	6°	8°	7°	
All	Dimensi	ions in	mm	

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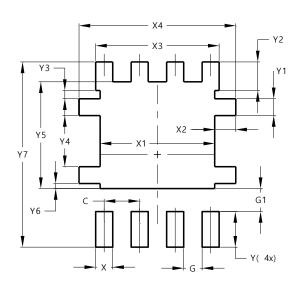


# **Suggested Pad Layout**

Please see http://www.diodes.com/package-outlines.html for the latest version.

Site 1:

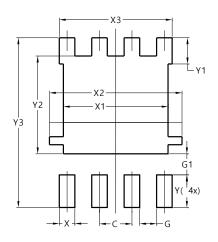
PowerDI5060-8



Dimensions	Value (in mm)
С	1.270
G	0.660
G1	0.820
Х	0.610
X1	4.100
X2	0.755
X3	4.420
X4	5.610
Y	1.270
Y1	0.600
Y2	1.020
Y3	0.295
Y4	1.825
Y5	3.810
Y6	0.180
Y7	6.610

Site 2:

PowerDI5060-8/SWP (Type UX)



Dimensions	Value		
Dimensions	(in mm)		
С	1.270		
G	0.660		
G1	0.820		
Х	0.610		
X1	4.100		
X2	5.190		
X3	4.420		
Y	1.270		
Y1	1.020		
Y2	3.810		
Y3	6.610		



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